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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## RENESAS

# MOS FIELD EFFECT TRANSISTOR $\mu PA2452$

PACKAGE DRAWING (Unit: mm)

### N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### DESCRIPTION

The  $\mu$  PA2452 is a switching device which can be driven directly by a 2.5 V power source.

This  $\mu$  PA2452 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### FEATURES

- 2.5 V drive available
- · Low on-state resistance
- $\begin{array}{l} R_{DS(on)1} = 17.5 \ m\Omega \ TYP. \ (V_{GS} = 4.5 \ V, \ I_{D} = 4.0 \ A) \\ R_{DS(on)2} = 18.5 \ m\Omega \ TYP. \ (V_{GS} = 4.0 \ V, \ I_{D} = 4.0 \ A) \\ R_{DS(on)3} = 21.0 \ m\Omega \ TYP. \ (V_{GS} = 3.1 \ V, \ I_{D} = 4.0 \ A) \\ R_{DS(on)4} = 25.0 \ m\Omega \ TYP. \ (V_{GS} = 2.5 \ V, \ I_{D} = 4.0 \ A) \end{array}$
- · Built-in G-S protection diode against ESD

### **ORDERING INFORMATION**

PART NUMBER	PACKAGE
$\mu$ PA2452TL	6PIN HWSON (4521)

### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	24.0	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±12.0	V
Drain Current (DC) <sup>Note1</sup>	D(DC)	±7.8	А
Drain Current (pulse) Note2	D(pulse)	±80.0	А
Total Power Dissipation (2 units) Note1	<b>P</b> T1	2.5	W
Total Power Dissipation (2 units) Note3	Рт2	0.7	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

Notes 1. Mounted on ceramic substrate of 50 cm<sup>2</sup> x 1.1 mm

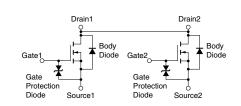
- **2.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
- **3.** Mounted on FR-4 board of 50 cm<sup>2</sup> x 1.6 mm
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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### EQUIVALENT CIRCUIT

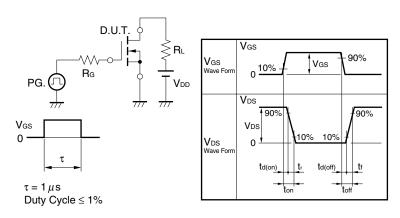


ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

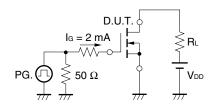
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 24.0 V, V <sub>GS</sub> = 0 V			10.0	μA
Gate Leakage Current	lgss	V <sub>GS</sub> = ±12.0 V, V <sub>DS</sub> = 0 V			±10.0	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 1.0 mA	0.5	0.7	1.5	V
Forward Transfer Admittance Note	<b>y</b> fs	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 4.0 A	3			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 4.0 A	12.0	17.5	21.5	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 4.0 A	12.5	18.5	22.5	mΩ
	RDS(on)3	V <sub>GS</sub> = 3.1 V, I <sub>D</sub> = 4.0 A	15.8	21.0	26.5	mΩ
	RDS(on)4	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 4.0 A	16.8	25.0	30.0	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10.0 V		390		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		130		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		90		pF
Turn-on Delay Time	<b>t</b> d(on)	V <sub>DD</sub> = 20.0 V		20		ns
Rise Time	tr	I <sub>D</sub> = 4.0 A		120		ns
Turn-off Delay Time	td(off)	V <sub>GS</sub> = 4.0 V		180		ns
Fall Time	tr	R <sub>G</sub> = 6.0 Ω		210		ns
Total Gate Charge	QG	V <sub>DD</sub> = 20.0 V		6.5		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 4.0 V		1.0		nC
Gate to Drain Charge	Qgd	ID = 7.8 A		3.0		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 7.8 A, VGS = 0 V		0.8		V
Reverse Recovery Time	trr	IF = 7.8 A, VGS = 0 V		210		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		330		nC

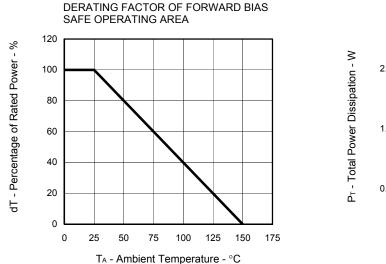
**Note** Pulsed: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

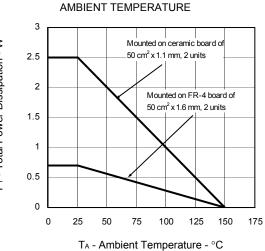
### **TEST CIRCUIT 1 SWITCHING TIME**



### TEST CIRCUIT 2 GATE CHARGE

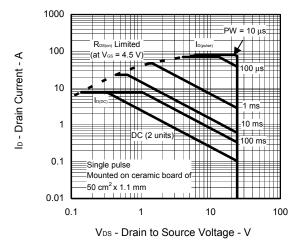


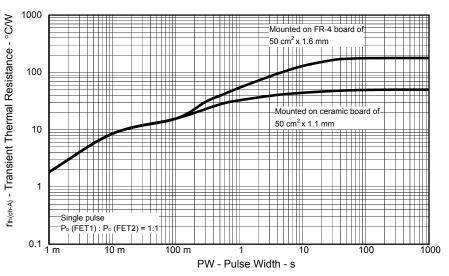




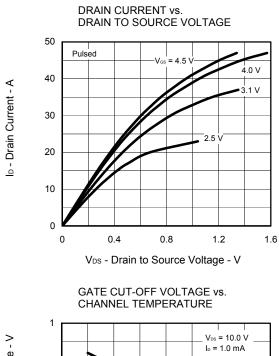
TOTAL POWER DISSIPATION vs.

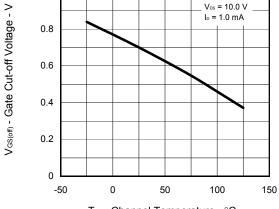
FORWARD BIAS SAFE OPERATING AREA





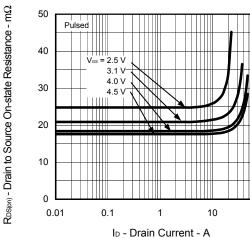
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



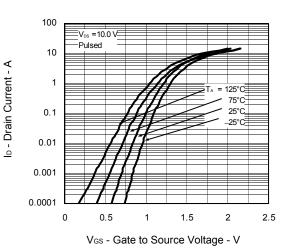


T<sub>ch</sub> - Channel Temperature - °C

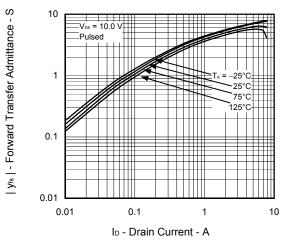
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



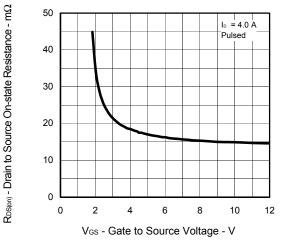
FORWARD TRANSFER CHARACTERISTICS



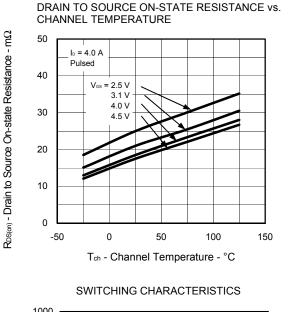
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

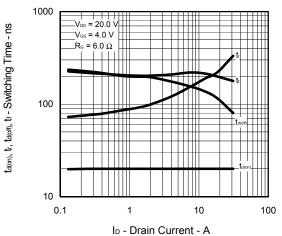


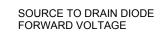
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

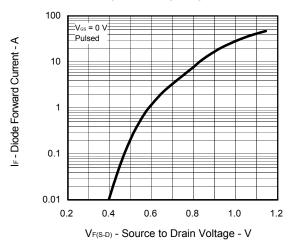


100

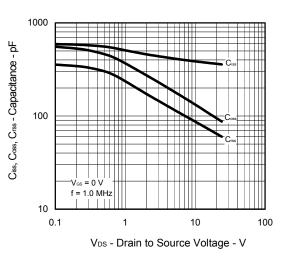




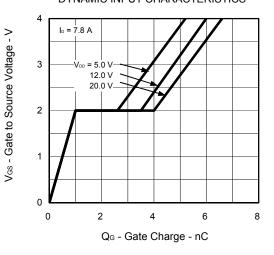




CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



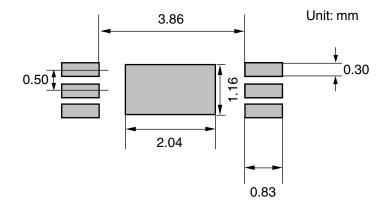
DYNAMIC INPUT CHARACTERISTICS



### <Notes for using this device safely>

When you use this device, in order to prevent a customer's hazard and damage, use it with understanding the following contents. If used exceeding recommended conditions, there is a possibility of causing failure of the device and characteristic degradation.

- 1. When you mount the device on a substrate, carry out within our recommended soldering conditions of infrared reflow. If mounted exceeding the conditions, the characteristic of a device may be degraded and it may result failure.
- 2. When you wash the device mounted the substrate, carry out within our recommended conditions. If washed exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 3. When you use ultrasonic wave to substrate after the device mounting, prevent from touching a resonance generator directly. If it touches, the characteristic of a device may be degraded and it may result in failure.
- 4. Please refer to **Figure 1** as an example of the land pattern. Optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.



### Figure 1. Example of the land pattern

5. This device is very thin device and should be handled with caution for mechanical stress. The rate of distortion applied to the device should become below 2000  $\mu\epsilon$ .<sup>Note1</sup> If the rate of distortion exceeds 2000  $\mu\epsilon$ , the characteristic of a device may be degraded and it may result in failure.

### Figure 2. Direction of substrate and stress

The substrate that mounted the device is on a stand with a support width of 24 mm. The device is turned downward. The stress is applied from a top.

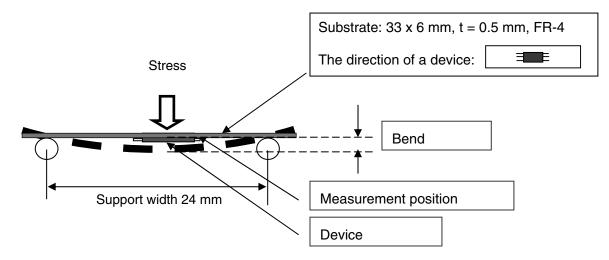
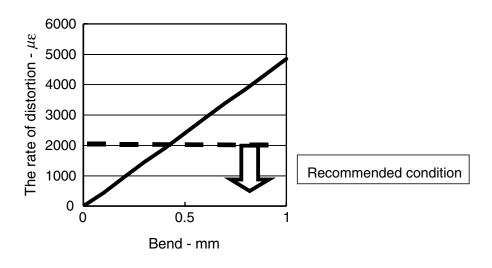


Figure 3. Example of the bend and the rate of distortion Note2



Note 1. Definition (written as  $\epsilon$  in this document)

 $\epsilon = (I - I_0)/I_0$ 

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lo: Distance for two arbitrary points before receiving stress.

I: Distance above-mentioned when receiving stress.

**2.** The relation of the distortion and the bend changes with several conditions, such as a size of substrate and so on.

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